AUTOMOTIVE

RoHS

COMPLIANT

HALOGEN FREE



Vishay General Semiconductor

High Current Density Surface Mount Ultrafast Rectifiers



LINKS TO ADDITIONAL RESOURCES

Cathode



PRIMARY CHARACTERISTICS				
I _{F(AV)}	2 x 2.0 A			
V _{RRM}	100 V, 150 V			
I _{FSM} 40 A				
t _{rr}	25 ns			
V _F at I _F = 2.0 A	0.77 V			
T _J max.	175 °C			
Package	SMPC (TO-277A)			
Circuit configurations	Common cathode			

FEATURES

- Very low profile typical height of 1.1 mm
- · Ideal for automated placement
- Oxide planar chip junction
- Ultrafast recovery times for high frequency
- Low forward voltage drop, low power loss
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available
 - Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in high frequency rectification and freewheeling application in switching mode converters and inverters for consumer computer, automotive, and telecommunication applications.

MECHANICAL DATA

Case: SMPC (TO-277A)

Molding compound meets UL 94 V-0 flammability rating Base P/NHM3_X - halogen-free, RoHS-compliant and

AEC-Q101 qualified

("_X" denotes revision code e.g. A, B,....)

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

HM3 suffix meets JESD 201 class 2 whisker test

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER		SYMBOL	UH4PBC	UH4PCC	UNIT	
Device marking code			H4BC	H4CC		
Maximum repetitive peak reverse voltage		V _{RRM}	100	150	V	
Maximum average forward rectified current (fig. 1)	total device		4.0		А	
	per diode	I _{F(AV)}	2.0			
Peak forward surge current 10 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	40		А	
Operating junction and storage temperature range		T _J , T _{STG}	-55 to +175		°C	



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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I _F = 1.0 A	T _A = 25 °C	V _F ⁽¹⁾	0.84	-	V
	I _F = 2.0 A			0.93	1.05	
	I _F = 1.0 A	T _A = 125 °C		0.68	-	
	I _F = 2.0 A			0.77	0.85	
Reverse current per diode	Poted V	T _A = 25 °C	I _R ⁽²⁾	-	5	μΑ
	Rated V _R	T _A = 125 °C		6.4	25	
Maximum reverse recovery time per diode	I _F = 0.5 A, I _R = 1.0 A, I _{rr} = 0.25 A			20	25	no
Typical reverse recovery time per diode	$I_F = 1.0 \text{ A}, \text{ dI/dt} = 50 \text{ A/}\mu\text{s}, \\ V_R = 30 \text{ V}, I_{rr} = 0.1 I_{RM}$		t _{rr}	24	-	ns
Typical softness factor (t _b /t _a)per diode	$I_F = 2 \text{ A, dI/dt} = 200 \text{ A/}\mu\text{s,}$ $V_R = 200 \text{ V, } I_{rr} = 0.1 I_{RM}$ $T_A = 125 \text{ °C}$		S	0.3	-	-
Typical reverse recovery current per diode			I _{RM}	5.4	-	Α
Typical stored charge per diode			Q _{rr}	88	-	nC
Typical junction capacitance per diode	4.0 V, 1 MHz		CJ	21	-	pF

Notes

 $^{(1)}$ Pulse test: 300 μs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL	UH4PBC	UH4PCC	UNIT		
Typical thermal resistance per device	R ₀ JA (1)	60		°C/W		
Typical thermal resistance per device	$R_{ heta JL}$	4				

Note

(1) Units mounted on recommended PCB 1 oz. pad layout

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
UH4PCCHM3_A/H (1)	0.10	Н	1500	7" diameter plastic tape and reel		
UH4PCCHM3_A/I (1)	0.10	İ	6500	13" diameter plastic tape and reel		

Note

(1) AEC-Q101 qualified

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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

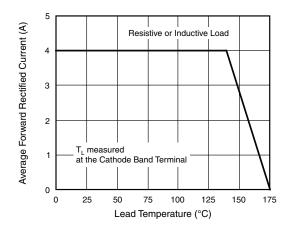


Fig. 1 - Maximum Forward Current Derating Curve

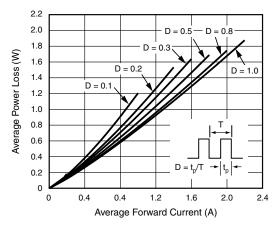


Fig. 2 - Forward Power Loss Characteristics Per Diode

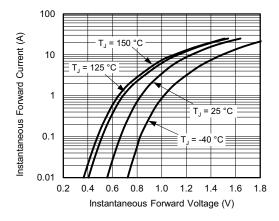


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

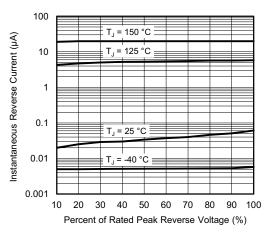


Fig. 4 - Typical Reverse Leakage Characteristics Per Diode

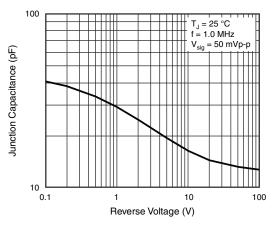


Fig. 5 - Typical Junction Capacitance Per Diode

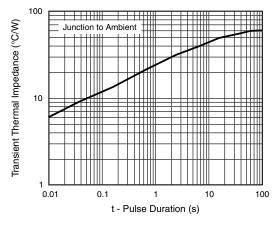
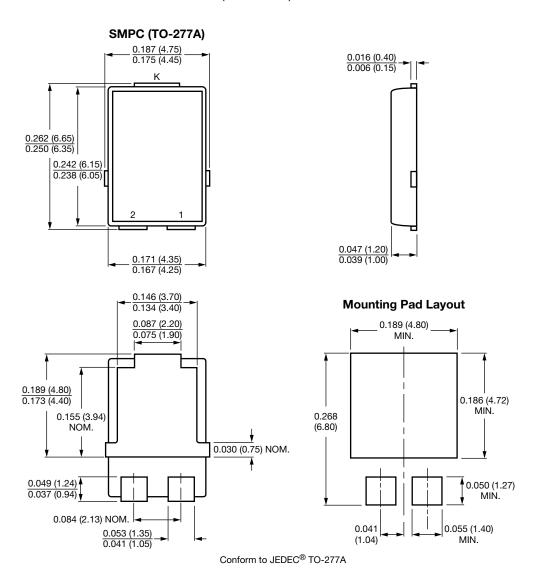


Fig. 6 - Typical Transient Thermal Impedance Per Device



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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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